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## (WO/2002/101841) III GROUP NITRIDE BASED SEMICONDUCTOR LUMINESCENT ELEMENT

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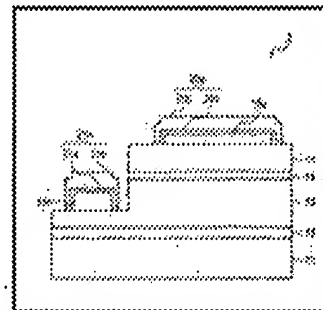
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**Title:** III GROUP NITRIDE BASED SEMICONDUCTOR LUMINESCENT ELEMENT

**Abstract:** A III Group nitride based semiconductor luminescent element of flip chip type, wherein a Au layer is provided via a Ti layer on the surface of a p-side electrode and the surface of an n-side electrode.



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